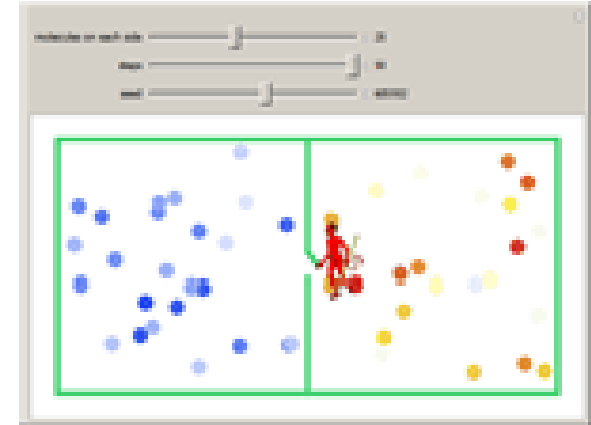
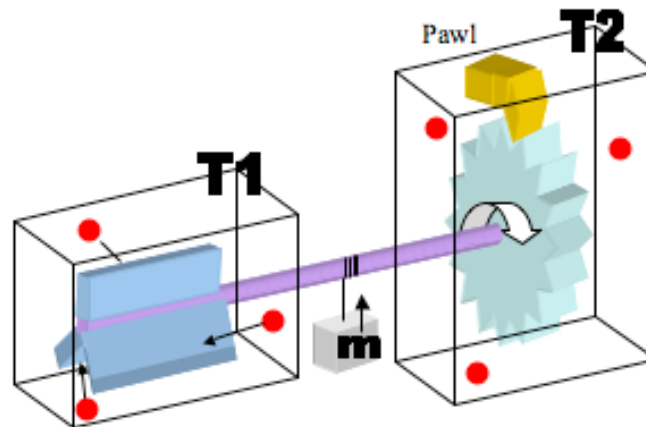


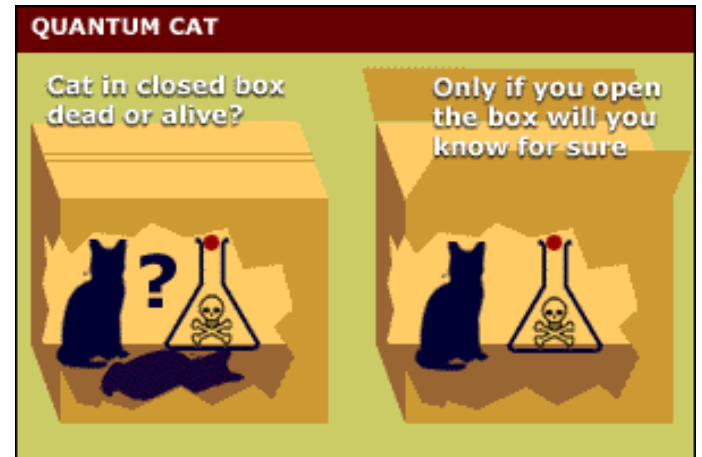
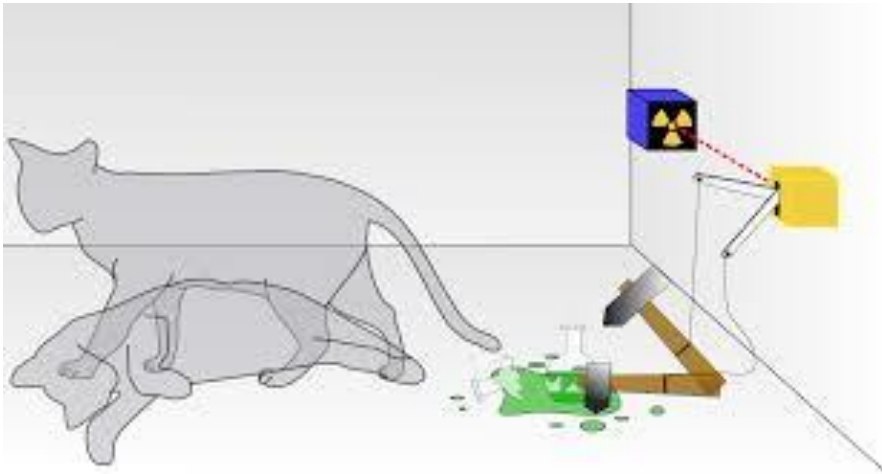
Maxwell Demon



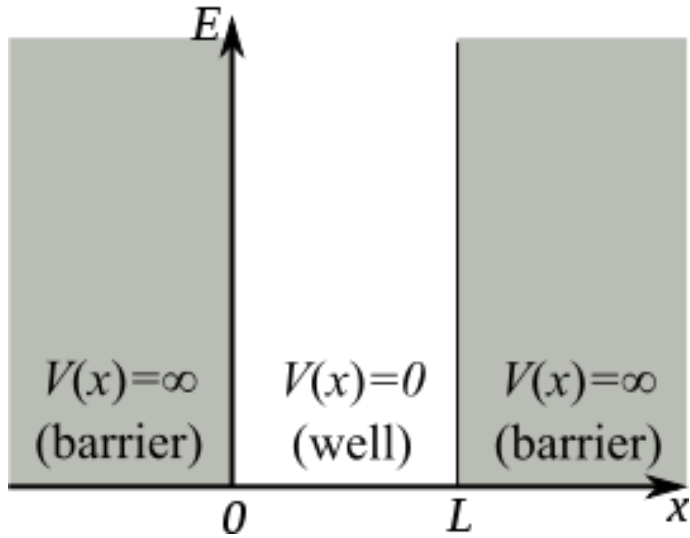
Brownian ratchet (Feynman 1962)



Quantum Cat



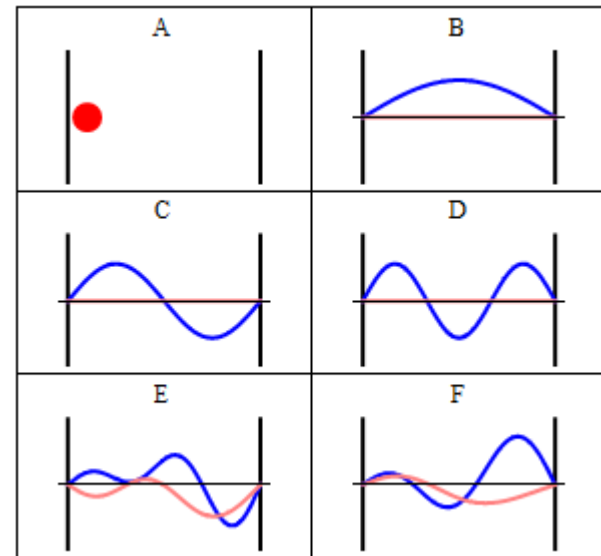
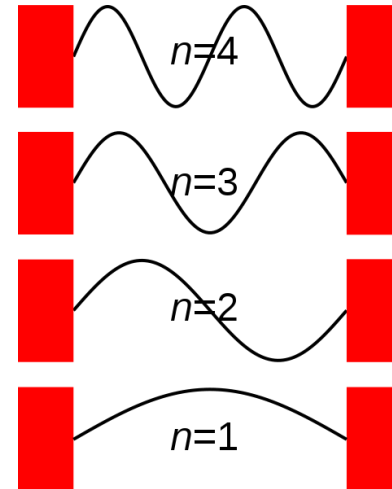
Quantum box



$$\psi_n(x) = C \sin(k_n x) = C \sin\left(\frac{n}{L} x\right), \quad n=1,2,3,\dots$$

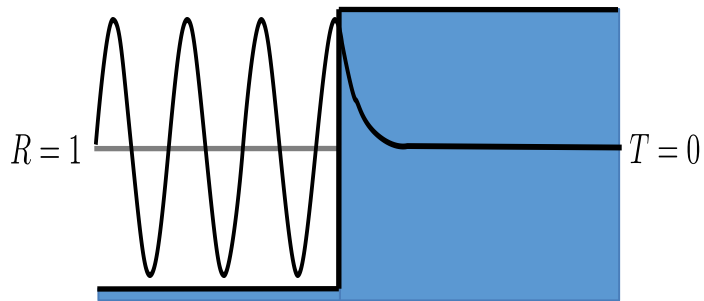
$$k_n = \sqrt{\frac{2mE_n}{\hbar^2}}$$

$$E_n = \frac{n^2 \hbar^2}{2mL^2}$$

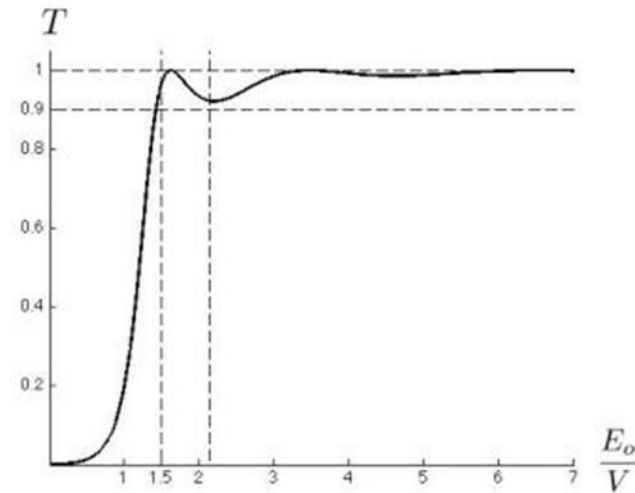
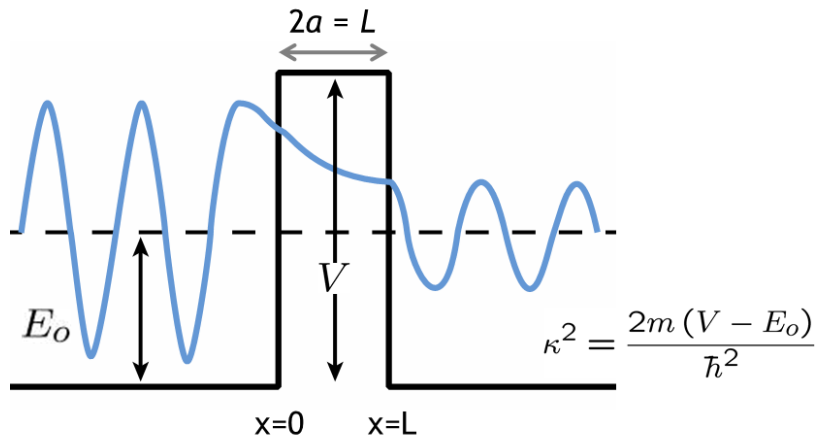
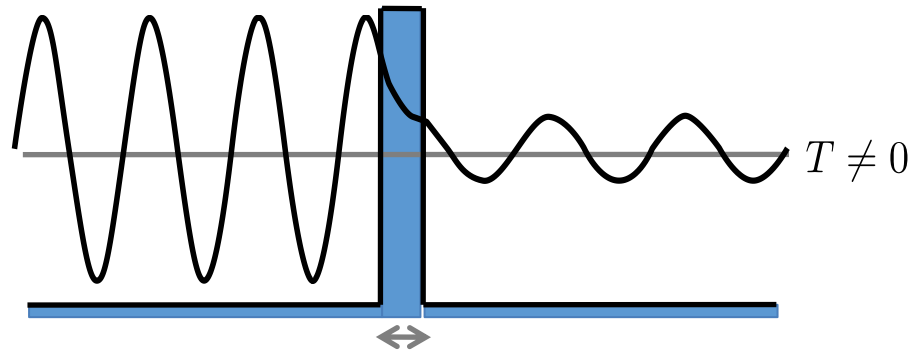


Quantum Tunneling Through a Thin Potential Barrier

Total Reflection at Boundary



Frustrated Total Reflection (Tunneling)

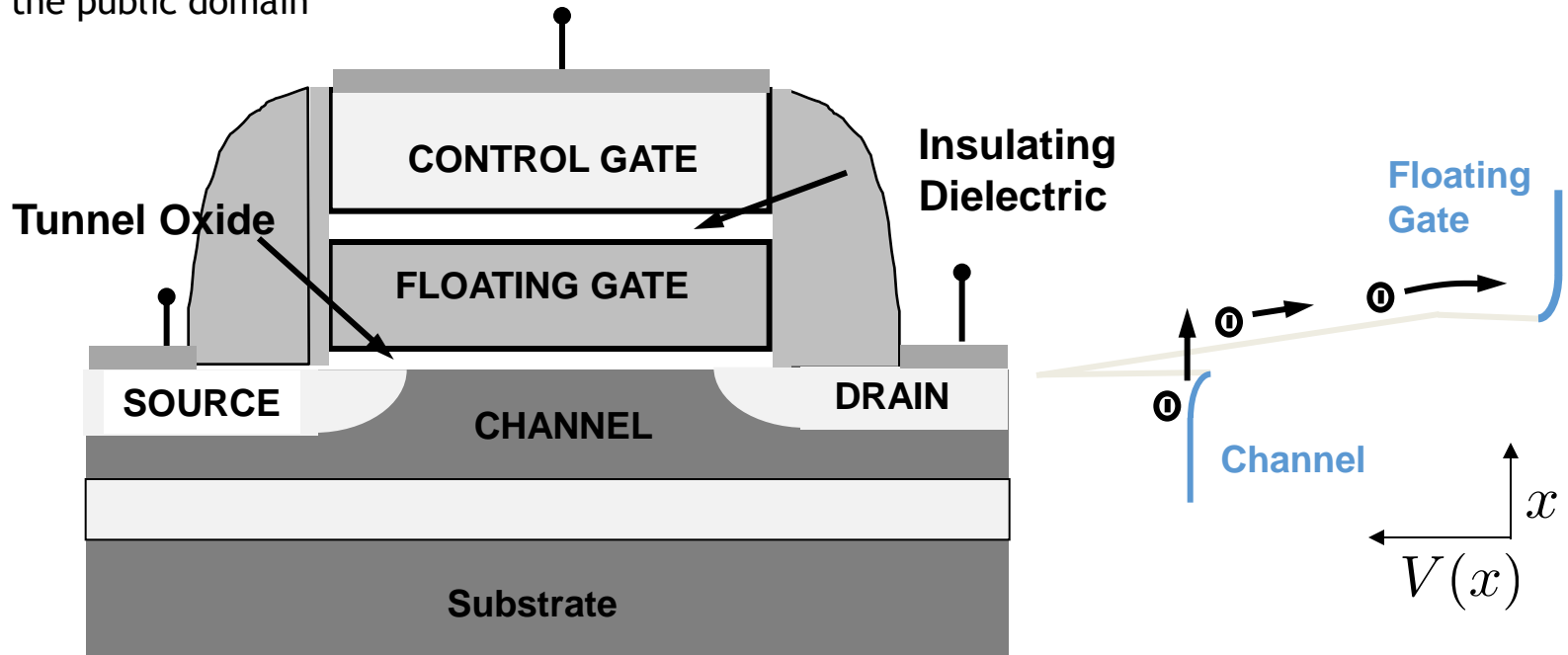
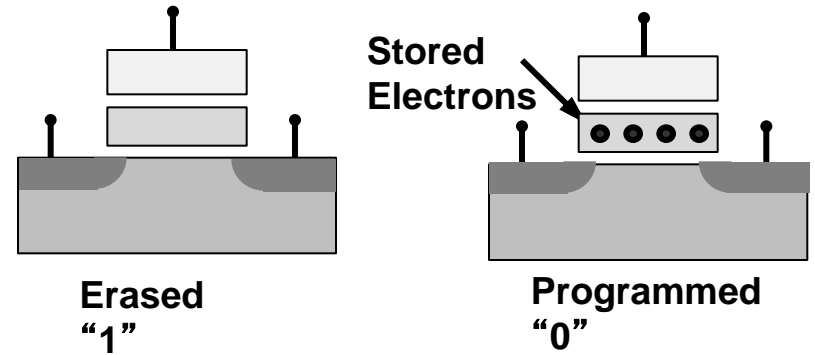


$$T = \left| \frac{F}{A} \right|^2 = \frac{1}{1 + \frac{1}{4} \frac{V^2}{E_o(V - E_o)} \sinh^2(2\kappa a)}$$

Flash Memory

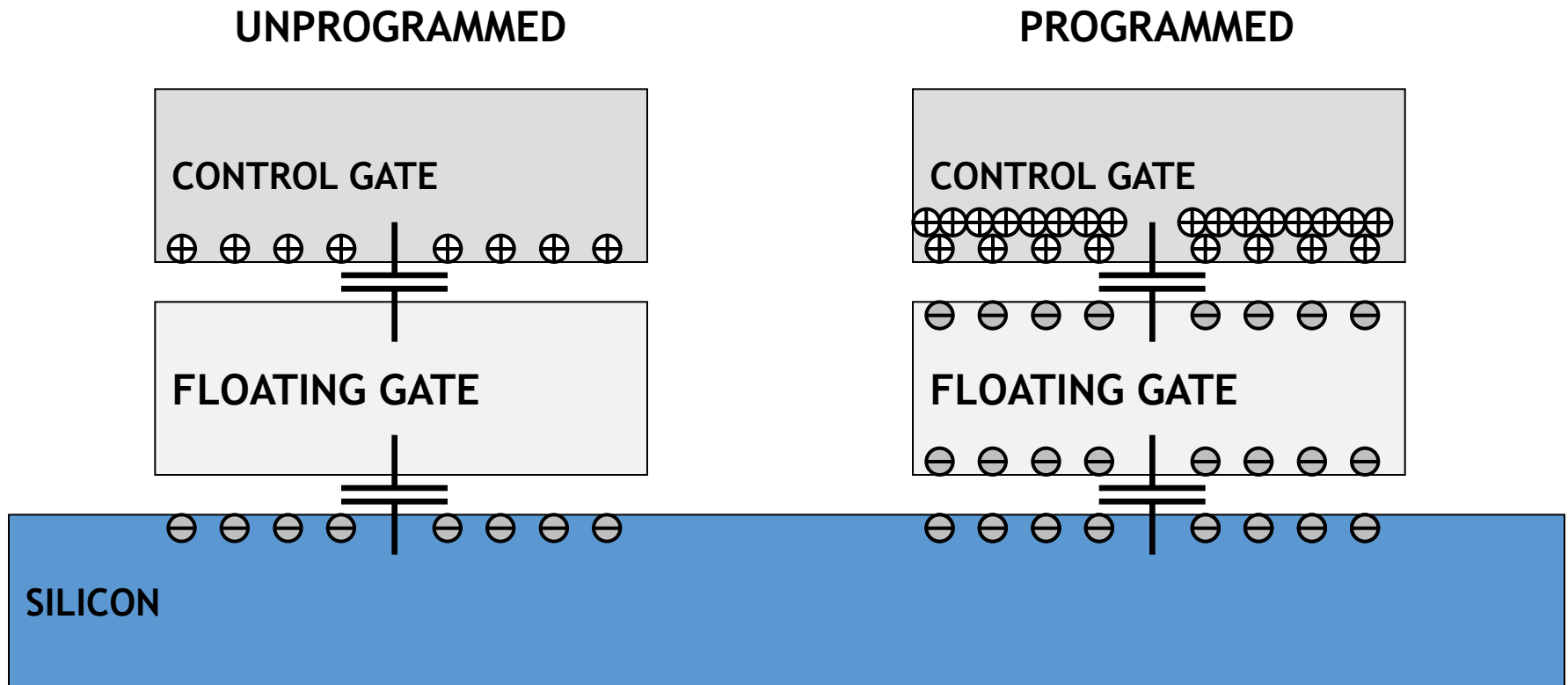


Image is in the public domain



Electrons tunnel preferentially when a voltage is applied

Reading Flash Memory



To obtain the same channel charge, the programmed gate needs a higher control-gate voltage than the unprogrammed gate

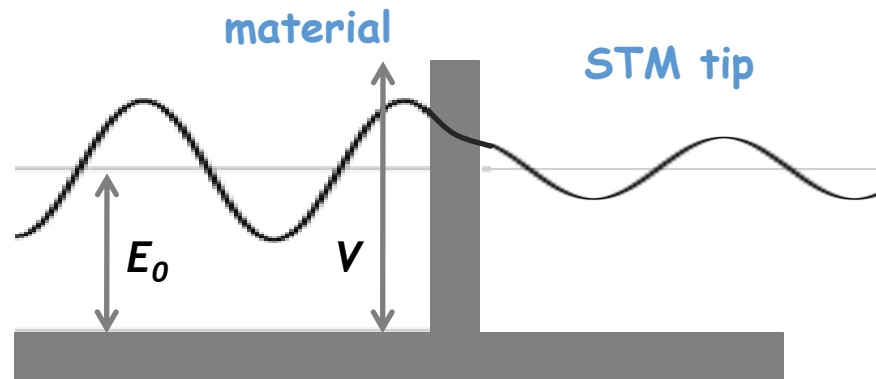
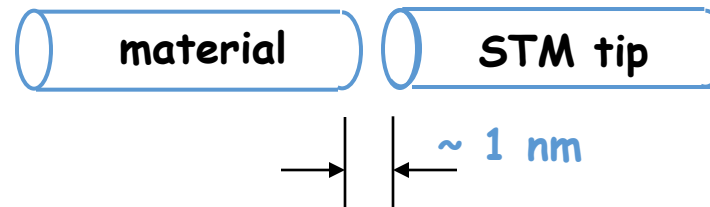
How do we WRITE Flash Memory ?

Application of Tunneling:

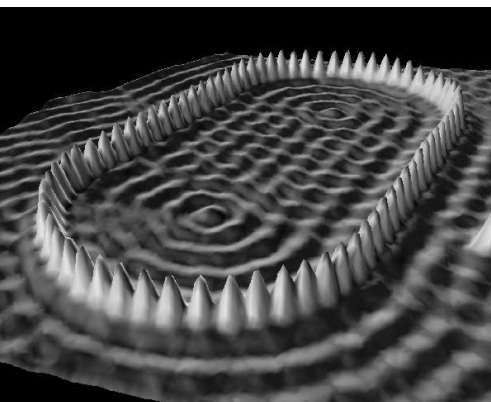
Scanning Tunneling Microscopy (STM)

Due to the quantum effect of “barrier penetration,” the electron density of a material extends beyond its surface:

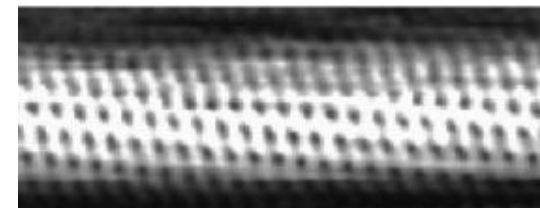
One can exploit this to measure the electron density on a material's surface:



Sodium atoms on metal:



Single walled carbon nanotube:



← **STM images** →

Image originally created by IBM Corporation

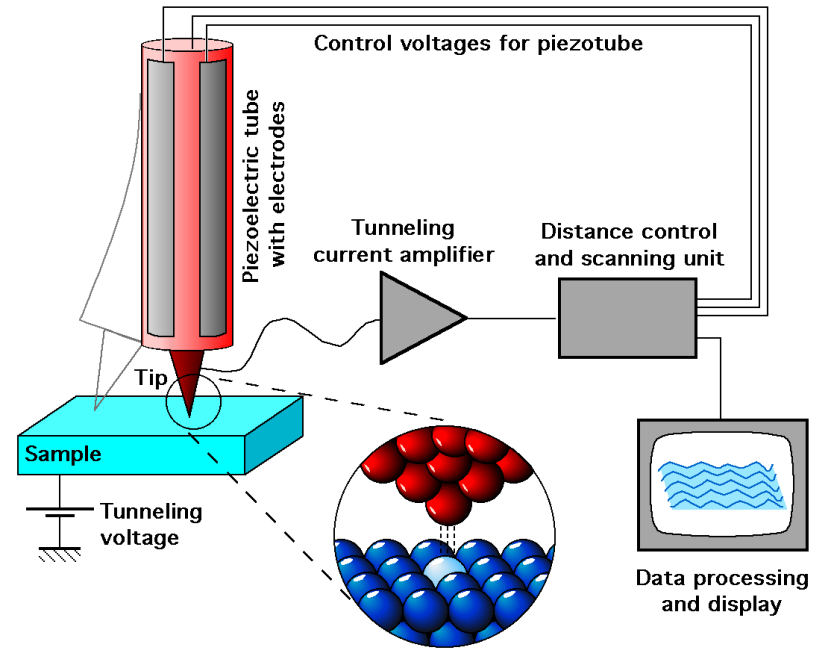
Image is in the public domain

Scanning Tunneling Microscopes

The Scanning Tunneling
Microscope was invented in 1981
by Gerd Binnig and Heinrich
Rohrer

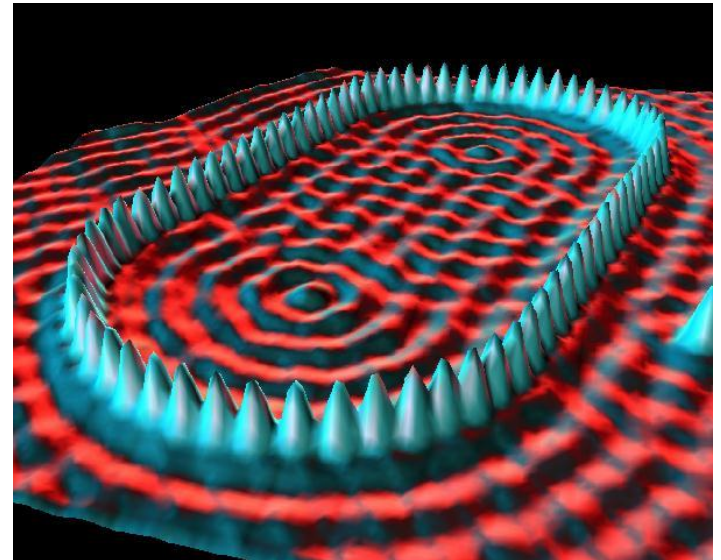
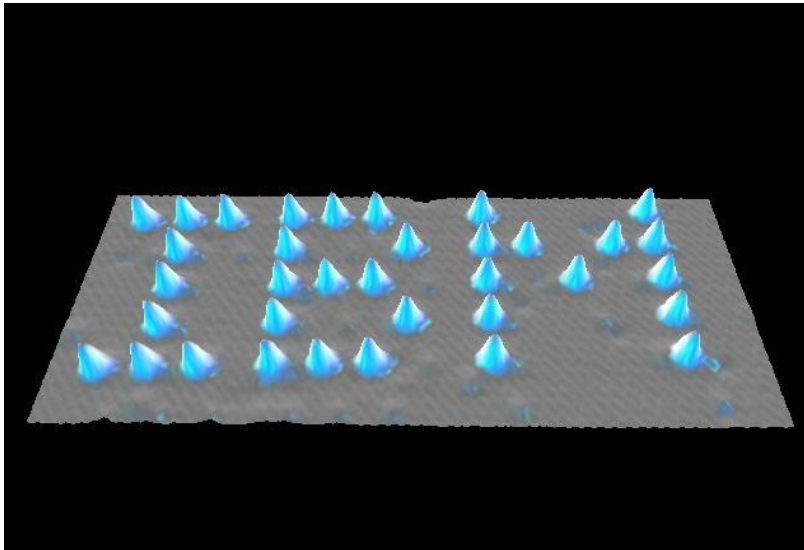
When a metal tip, usually made of
tungsten or platinum-iridium, is
brought within .4-.7nm of the
sample, electrons tunnel across
the gap and create a current in the
tip

This current is then fed to a
computer and used to generate an
image of the atomic surface of the
sample



At this distance the coulomb force between the tip and an atom of the sample is actually enough to move the atom

This has allowed physicists to create images and structures on the atomic level



Images courtesy of IBM

Force Sensors

A UK company is developing flexible force sensors that use quantum tunneling

These sensors are made out of Quantum Tunneling Composite materials

QTC's are essentially non-conducting in their normal state

When flexed by an applied force, the atoms of the QTC are brought close enough so that tunneling can occur

Tunneling changes the QTC from an insulator to a conductor with a predictable exponential decay in resistance

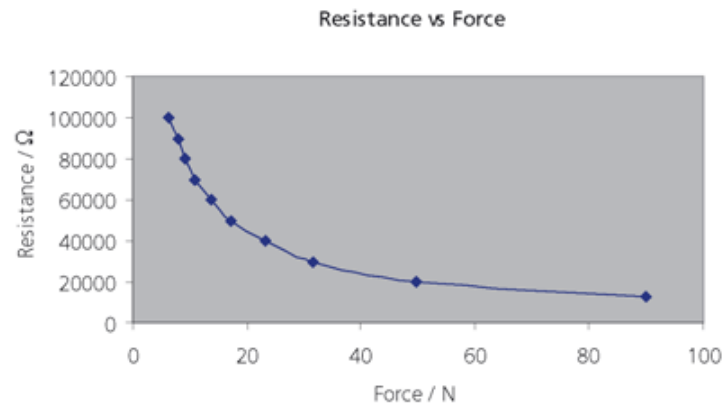
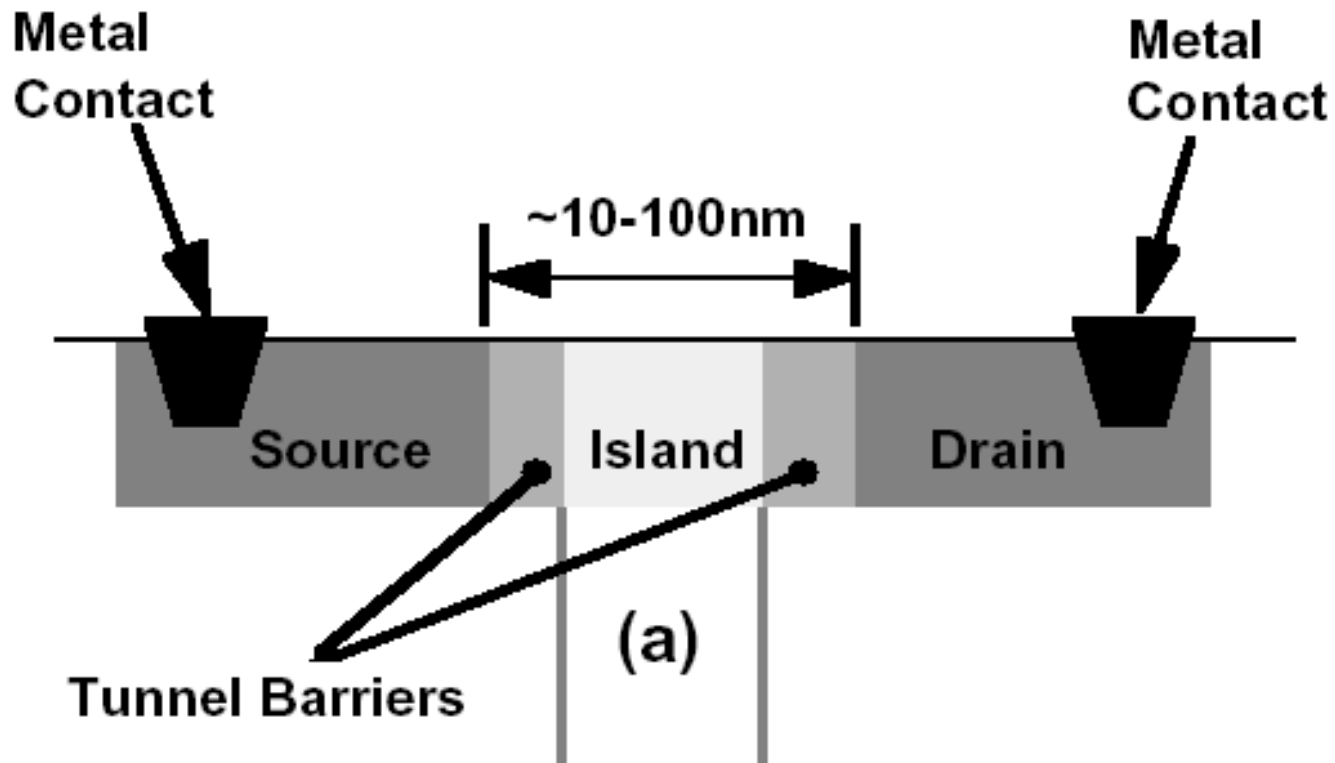


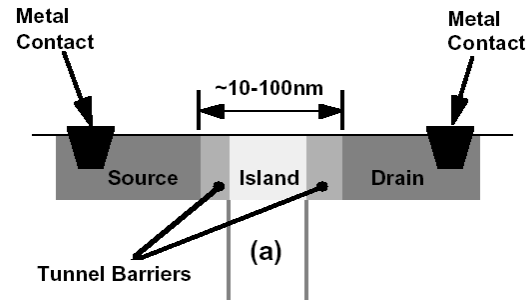
Image
courtesy of
Peratech

Resonant Tunnelling Diodes

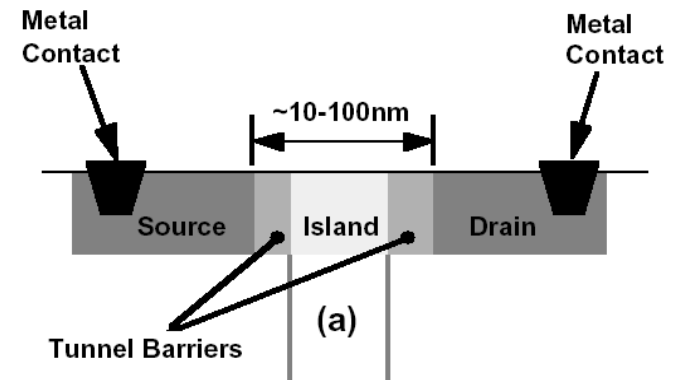
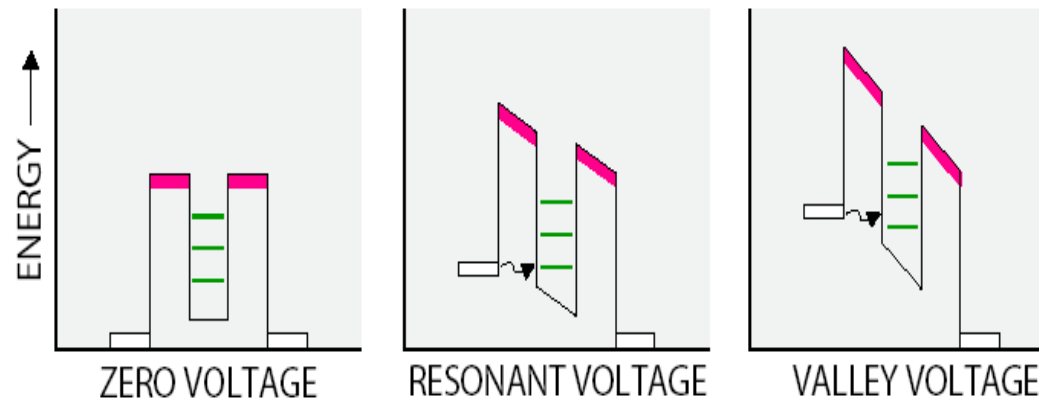
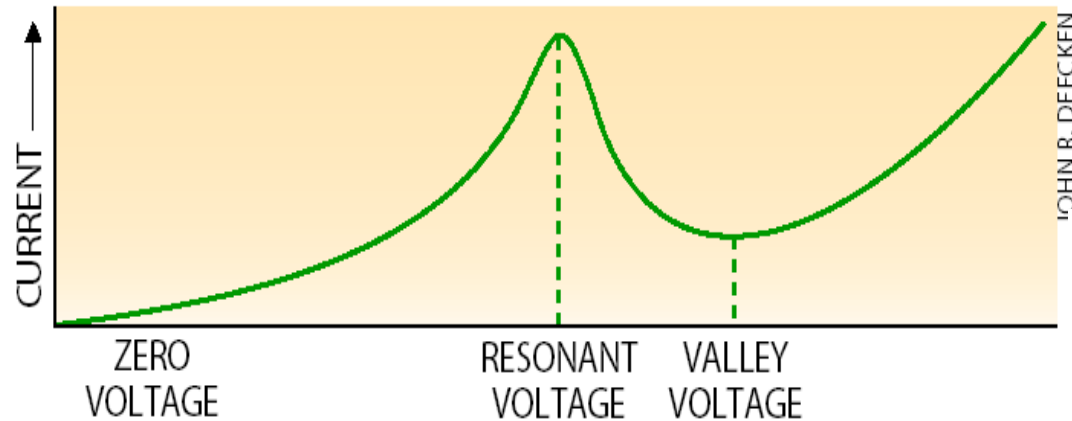


Resonant Tunnelling Diodes

- Fundamentally different operating principle
 - Quantisation
 - Quantum tunnelling
- Computation comes from Negative Differential Resistance (NDR)



Negative Differential Resistance



Need high peak to
Valley Current Ratio
(PVCR)
PVCR of 2-4
desirable